

N-Channel Shielded Gate PowerTrench[®] MOSFET

General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench[®] process that

incorporates Shielded Gate technology. This process has been

Thermal Characteristics

FAIRCHILD

FDMS86201

Features

120 V, 49 A, 11.5 mΩ

Shielded Gate MOSFET Technology

• Max $r_{DS(on)}$ = 11.5 m Ω at V_{GS} = 10 V, I_D = 11.6 A

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case		1.2	°C/W
Rein	Thermal Resistance, Junction to Ambient	(Note 1a)	50	°C/w

Package Marking and Ordering Information

Device Marking Device		Package	Reel Size	Tape Width	Quantity
FDMS86201	FDMS86201	Power 56	13 "	12 mm	3000 units

D

D

D

D

Units

V

V

А

mJ

W

°C

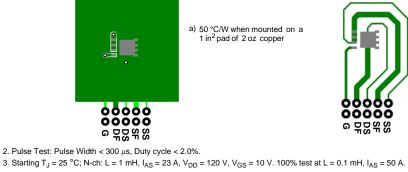
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FDMS86201 N	
N-Channel	
Shielded (
V-Channel Shielded Gate PowerTrench[®]	
)
MOSFET	

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	octeristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \ \mu A, \ V_{GS} = 0 \ V$	120			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		95		mV/°C
IDSS	Zero Gate Voltage Drain Current	V _{DS} = 96 V, V _{GS} = 0 V			1	μA
I _{GSS}	Gate to Source Leakage Current, Forward	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			100	nA
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250 μA	2.0	2.6	4.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-10		mV/°C
	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 11.6 A		9.6	11.5	
r _{DS(on)}		V _{GS} = 6 V, I _D = 10.7 A		11.8	14.5	mΩ
		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 11.6 \text{ A}, \text{ T}_{J} = 125 \text{ °C}$		15.7	21.5	
9 _{FS}	Forward Transconductance	V _{DS} = 10 V, I _D = 11.6 A		39		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance			2056	2735	pF
C _{oss}	Output Capacitance	V _{DS} = 60 V, V _{GS} = 0 V, f = 1 MHz		322	430	pF
C _{rss}	Reverse Transfer Capacitance			15	25	pF
R _g	Gate Resistance			1.2		Ω
Switching	g Characteristics					
t _{d(on)}	Turn-On Delay Time			13	24	ns
t _r	Rise Time	V _{DD} = 60 V, I _D = 11.6 A,		7.7	16	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		27	44	ns
t _f	Fall Time	1 – – – – – – – – – – – – – – – – – – –		7.1	15	ns
Qg	Total Gate Charge	V _{GS} = 0 V to 10 V		32	46	nC
Qg	Total Gate Charge	$V_{GS} = 0 \text{ V to 5 V} \text{V}_{DD} = 60 \text{ V},$		18	26	nC
Q _{gs}	Gate to Source Charge	I _D = 11.6 A		8.1		nC
	Gate to Drain "Miller" Charge			7.1		nC

V _{SD} Source to Drain Diode Forwa	Source to Drain Diado, Forward Voltage	$V_{GS} = 0 V, I_{S} = 2 A$	(Note 2)	0.69	1.2	V	
	Source to Drain Diode Polward voltage	$V_{GS} = 0 V, I_{S} = 11.6 A$	(Note 2)	0.78	1.3	v	
t _{rr}	rr Reverse Recovery Time		luc	66	106	ns	
Q _{rr}	Reverse Recovery Charge	I _F = 11.6 A, di/dt = 100 A/μs		88	140	nC	

Notes: 1. R_{8JA} is determined with the device mounted on a 1in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{8JC} is guaranteed by design while R_{8CA} is determined by the user's board design.

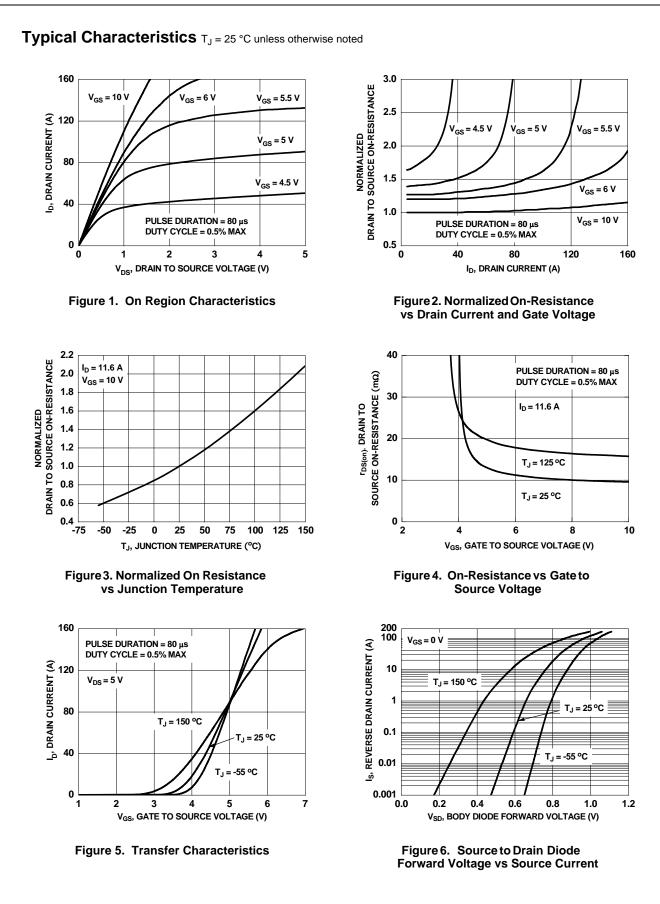


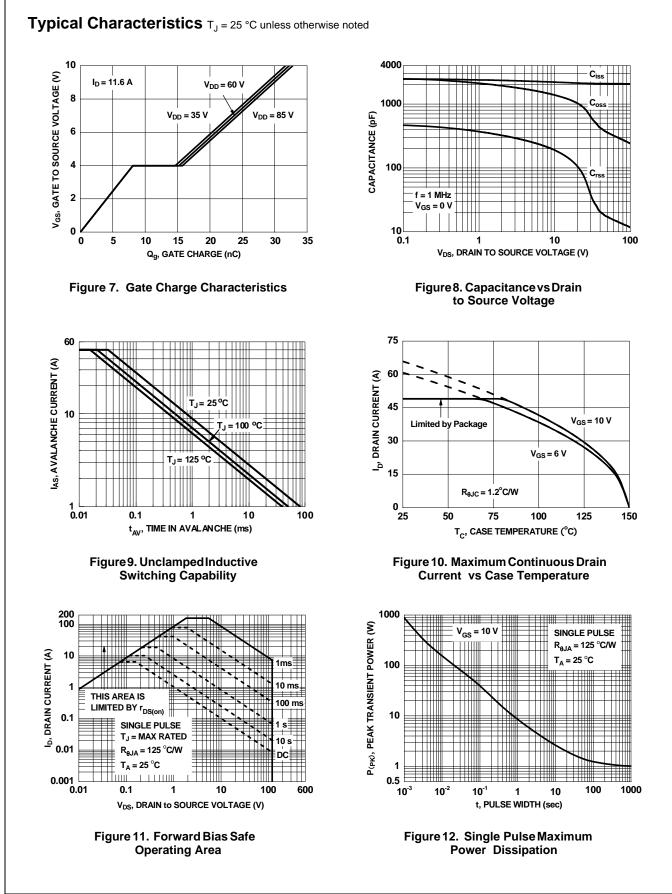
a) 50 °C/W when mounted on a 1 in² pad of 2 oz copper



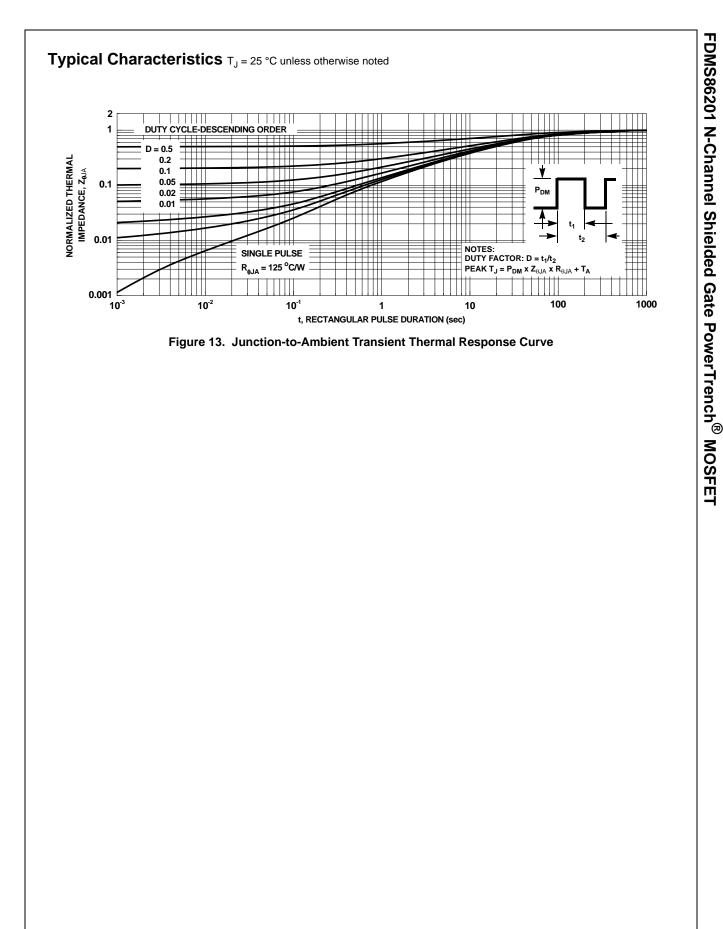


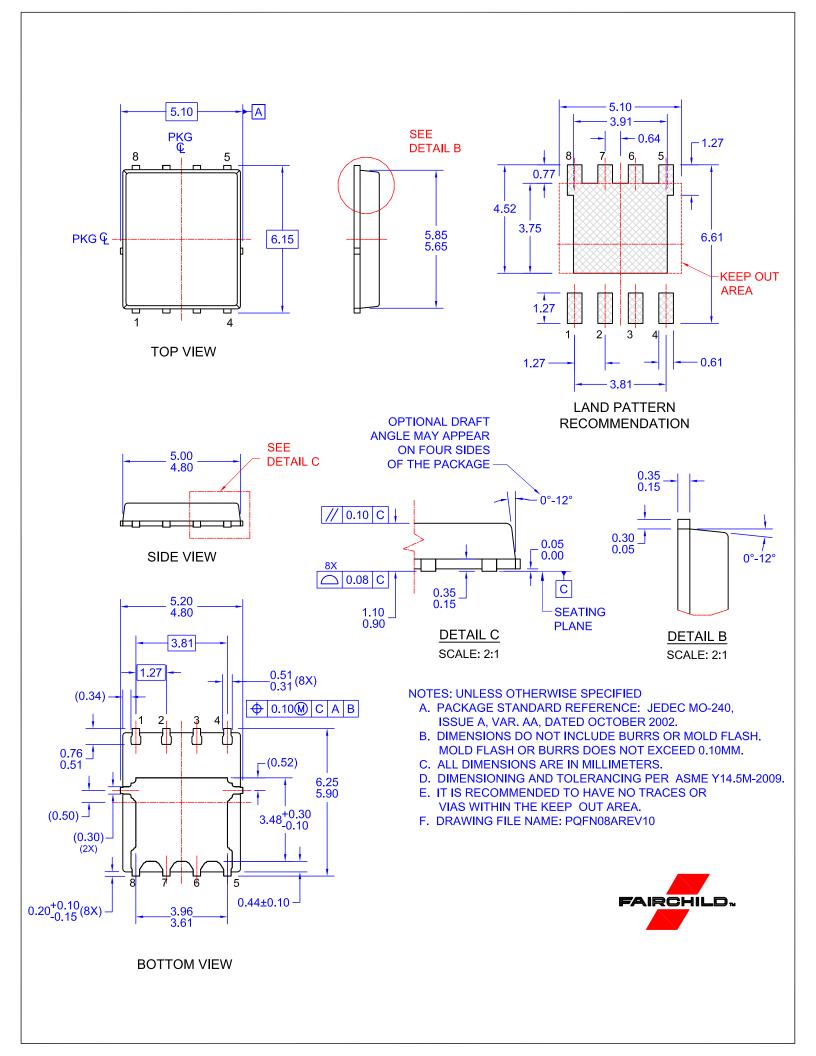
b) 125 °C/W when mounted on a minimum pad of 2 oz copper.





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